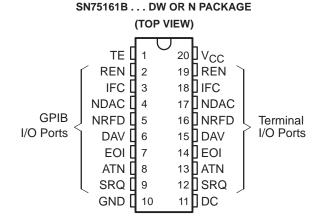
SLLS005B - OCTOBER 1980 - REVISED MAY 1995

- Meets IEEE Standard 488-1978 (GPIB)
- 8-Channel Bidirectional Transceivers
- Power-Up/Power-Down Protection (Glitch Free)
- **Designed to Implement Control Bus** Interface
- **SN75161B Designed for Single Controller**
- SN75162B Designed for Multiple **Controllers**
- High-Speed, Low-Power Schottky Circuitry
- Low Power Dissipation . . . 72 mW Max Per Channel
- Fast Propagation Times . . . 22 ns Max
- **High-Impedance pnp Inputs**
- Receiver Hysteresis . . . 650 mV Typ
- **Bus-Terminating Resistors Provided on Driver Outputs**
- No Loading of Bus When Device Is Powered Down ($V_{CC} = 0$)

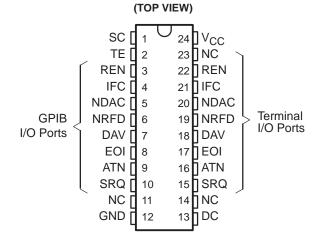
description

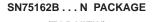
The SN75161B and SN75162B eight-channel, general-purpose interface bus transceivers are monolithic, high-speed, low-power Schottky devices designed to meet the requirements of IEEE Standard 488-1978. Each transceiver is designed to provide the bus-management and data-transfer signals between operating units of a single- or multiple-controller instrumentation system. When combined with the SN75160B octal bus transceiver, the SN75161B or SN75162B provides the complete 16-wire interface for the IEEE-488 bus.

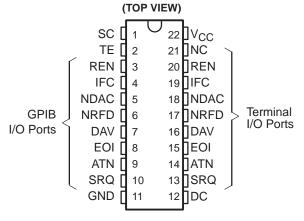
The SN75161B and SN75162B feature eight driver-receiver pairs connected in a front-to-back configuration to form input/output (I/O) ports at both the bus and terminal sides. A powerup/-down disable circuit is included on all bus and receiver outputs. This provides glitch-free operation during V_{CC} power up and power down.



SN75162B...DW PACKAGE







NC-No internal connection



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description (continued)

The direction of data through these driver-receiver pairs is determined by the DC, TE, and SC (on SN75162B) enable signals. The SC input on the SN75162B allows the REN and IFC transceivers to be controlled independently.

The driver outputs (GPIB I/O ports) feature active bus-terminating resistor circuits designed to provide a high impedance to the bus when supply voltage V_{CC} is 0. The drivers are designed to handle loads up to 48 mA of sink current. Each receiver features pnp transistor inputs for high input impedance and hysteresis of 400 mV for increased noise immunity. All receivers have 3-state outputs to present a high impedance to the terminal when disabled.

The SN75161B and SN75162B are characterized for operation from 0°C to 70°C.

Function Tables

SN75161B RECEIVE/TRANSMIT

	CONTROLS	6		BUS-MAN	NAGEMENT	CHANNELS		DATA-TRANSFER CHANNELS		
DC	TE	ATN [†]	ATN†	SRQ	REN	IFC	EOI	DAV	NDAC	NRFD
				(Controlle	ed by DC)			(C	ontrolled by	TE)
Н	Н	Н	R	т	R	R	Т	_	R	R
Н	Н	L	, r	·	IX	K	R	'	IX.	
L	L	Н	т.	R	Т	+	R	R	T	_
L	L	L	ľ	ĸ		I	Т	K	ī	ı
Н	L	Х	R	Т	R	R	R	R	Т	Т
L	Н	Χ	Т	R	Т	Т	Т	Т	R	R

H = high level, L = low level, R = receive, T = transmit, X = irrelevant

Direction of data transmission is from the terminal side to the bus side, and the direction of data receiving is from the bus side to the terminal side. Data transfer is noninverting in both directions.

SN75162B RECEIVE/TRANSMIT

	CON	TROLS			BUS-MANA	GEMENT C	HANNELS		DATA-TR	ANSFER CH	HANNELS
SC	DC	TE	ATN†	ATN†	SRQ	REN	IFC	EOI	DAV	NDAC	NRFD
				(Controll	(Controlled by DC)		(Controlled by SC)		(Controlled by TE)		TE)
	Н	Н	Н	R	Т			Т	т	R	R
	Н	Н	L	K	ı			R	'	K	K
	L	L	Н	т	R			R	R	т	_
	L	L	L	'	ĸ			Т	K	ı	'
	Н	L	Х	R	Т			R	R	Т	Т
	L	Н	Х	Т	R			Т	Т	R	R
Н						Т	Т				
L						R	R				

H = high level, L = low level, R = receive, T = transmit, X = irrelevant

Direction of data transmission is from the terminal side to the bus side, and the direction of data receiving is from the bus side to the terminal side. Data transfer is noninverting in both directions.



[†] ATN is a normal transceiver channel that functions additionally as an internal direction control or talk enable for EOI whenever the DC and TE inputs are in the same state. When DC and TE are in opposite states, the ATN channel functions as an independent transceiver only.

TATN is a normal transceiver channel that functions additionally as an internal direction control or talk enable for EOI whenever the DC and TE inputs are in the same state. When DC and TE are in opposite states, the ATN channel functions as an independent transceiver only.

CHANNEL-IDENTIFICATION TABLE

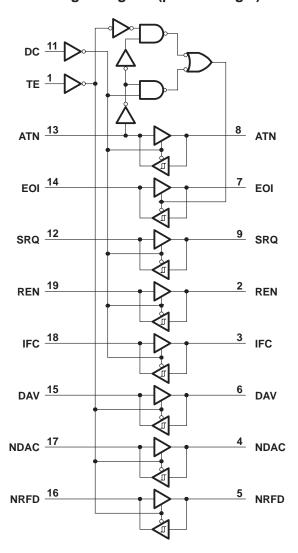
NAME	IDENTITY	CLASS
DC	Direction Control	
TE	Talk Enable	Control
sc	System Control (SN75162B only)	
ATN	Attention	
SRQ	Service Request	
REN	Remote Enable	Bus
IFC	Interface Clear	Management
EOI	End of Identity	
DAV	Data Valid	
NDAC	Not Data Accepted	Data
NRFD	Not Ready for Data	Transfer

SN75161B logic symbol[†]

DC 11 EN1/G4 TE 1 EN2/G5 EN3 ATN 13 8 — ATN **1** � П ∇ **1** 1 EOI 14 3 � EOI \triangleright **⊽** 3 \Box 1 9 SRQ \triangleright 1≎ SRQ ⊽ 1 1 П REN ______ 2 REN \triangleright **1** � П **71** 1 IFC 18 3 IFC \triangleright 1♀ П **⊽** 1 1 2≎ DAV \triangleright ⊽ 2 1 ╜ NDAC \triangleright <u>2</u> ♦ NDAC **∇**2 П 1 16 NRFD NRFD <u>2</u> ⇔ \triangleright ┰ **⊽**2

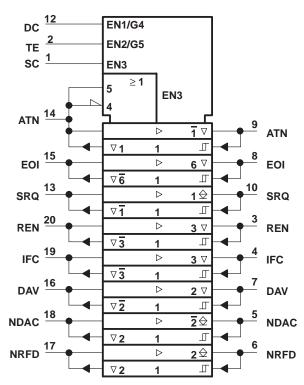
- [†]This symbol is in accordance with IEEE Std 91-1984 and IEC Publication 617-12.
- ∇ Designates 3-state outputs
- Designates passive-pullup outputs

SN75161B logic diagram (positive logic)



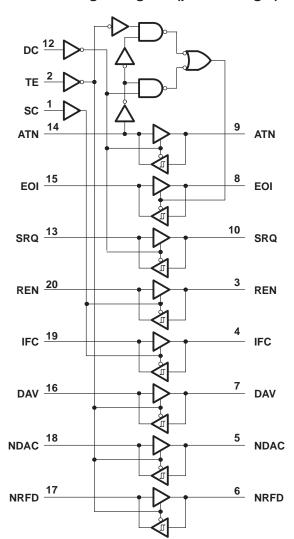


SN75162B logic symbol[†]



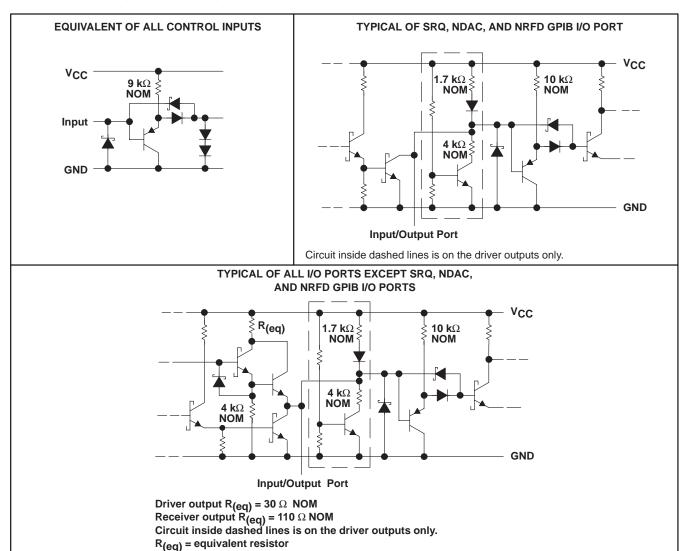
- †This symbol is in accordance with IEEE Std 91-1984 and IEC Publication 617-12.
- ∇ Designates 3-state outputs

SN75162B logic diagram (positive logic)



Pin numbers shown are for the N package.

schematics of inputs and outputs



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage, V _{CC} (see Note 1)	7 V
Input voltage, V _I	
Low-level driver output current, I _{OL}	100 mA
Continuous total power dissipation	. See Dissipation Rating Table
Operating free-air temperature range, T _A	0°C to 70°C
Storage temperature range, T _{stq}	–65°C to 150°C
Lead temperature 1,6 mm (1/16) inch from the case for 10 seconds	260°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: All voltage values are with respect to network ground terminal.



SN75161B, SN75162B OCTAL GENERAL-PURPOSE INTERFACE BUS TRANSCEIVERS

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DISSIPATION RATING TABLE

PACKAGE	$T_{\mbox{\scriptsize A}} \le 25^{\circ}\mbox{\scriptsize C}$ POWER RATING	DERATING FACTOR ABOVE T _A = 25°C	T _A = 70°C POWER RATING
DW (20 pin)	1125 mW	9.0 mW/°C	720 mW
DW (24 pin)	1350 mW	10.8 mW/°C	864 mW
N (20 pin)	1150 mW	9.2 mW/°C	736 mW
N (22 pin)	1700 mW	13.6 mW/°C	1088 mW

recommended operating conditions

			MIN	NOM	MAX	UNIT
Supply voltage, V _{CC}			4.75	5	5.25	V
High-level input voltage, V _{IH}		2			V	
Low-level input voltage, V _{IL}					0.8	V
I Pale Level and and account of	Bus ports with 3-state outputs			-5.2	mA	
High-level output current, I _{OH}	Terminal ports				-800	μΑ
Low lovel output output	Bus ports				48	A
Low-level output current, IOL	Terminal ports			16	mA	
Operating free-air temperature, TA		0		70	°C	

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electrical characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

	PARAMETER		TES	T CONDITIONS	MIN	TYP [†]	MAX	UNIT	
VIK	Input clamp voltage		$I_{I} = -18 \text{ mA}$			-0.8	-1.5	V	
V _{hys}	Hysteresis voltage (V _{IT+} - V _{IT-})	Bus	See Figure 7		0.4	0.65		V	
Vat	High-level output voltage	Terminal	$I_{OH} = -800 \mu A$	I _{OH} = -800 μA				V	
V _{OH} [‡]	r light-level output voltage	Bus	$I_{OH} = -5.2 \text{ mA}$		2.5	3.3		V	
VOL	Low-level output voltage	Terminal	$I_{OL} = 16 \text{ mA}$			0.3	0.5	V	
VOL	Low-level output voltage	Bus	$I_{OL} = 48 \text{ mA}$			0.35	0.5	V	
II	Input current at maximum input voltage	Terminal	V _I = 5.5 V	V _I = 5.5 V		0.2	100	μΑ	
llH	High-level input current	Terminal and	V _I = 2.7 V	V _I = 2.7 V		0.1	20	μΑ	
I _{IL}	Low-level input current	control inputs	V _I = 0.5 V			-10	-100	μΑ	
Vuon	V _{I/O(bus)} Voltage at bus port		Driver disabled	$I_{I(bus)} = 0$	2.5	3.0	3.7	V	
VI/O(bus)	voltage at bus port		Driver disabled	$I_{I(bus)} = -12 \text{ mA}$			-1.5	V	
				$V_{I(bus)} = -1.5 \text{ V to } 0.4 \text{ V}$	-1.3				
				$V_{I(bus)} = 0.4 \text{ V to } 2.5 \text{ V}$	0		-3.2		
		Power on	Driver disabled	V _{I(bus)} = 2.5 V to 3.7 V			2.5	mA	
I _{I/O(bus)}	Current into bus port	l ower on	Driver disabled	VI(bus) = 2.5 V to 5.7 V			-3.2	ША	
				$V_{I(bus)} = 3.7 \text{ V to 5 V}$	0		2.5		
				$V_{I(bus)} = 5 V \text{ to } 5.5 V$	0.7		2.5		
		Power off	$V_{CC} = 0$,	$V_{I(bus)} = 0 V to 2.5 V$			-40	μΑ	
los	Short-circuit output current	Terminal			-15	-35	-75	mA	
105	Short-circuit output current	Bus			-25	-50	-125	ША	
ICC	Supply current		No load,	TE, DE, and SC low			110	mA	
C _{I/O(bus)}	Bus-port capacitance		$V_{CC} = 5 \text{ V to } 0,$ $V_{I/O} = 0 \text{ to } 2 \text{ V},$	f = 1 MHz		16		pF	

[†] All typical values are at V_{CC} = 5 V, T_A = 25°C. ‡ V_{OH} applies for 3-state outputs only.

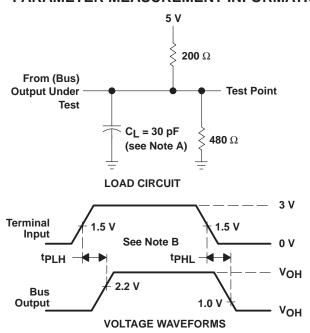
SN75161B, SN75162B OCTAL GENERAL-PURPOSE INTERFACE BUS TRANSCEIVERS

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switching characteristics, V_{CC} = 5 V, C_L = 15 pF, T_A = 25°C (unless otherwise noted)

	PARAMETER	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	MIN	TYP	MAX	UNIT
^t PLH	Propagation delay time, low- to high-level output	Terminal	Bus	C _L = 30 pF,		14	20	ns
^t PHL	Propagation delay time, high- to low-level output	Terminal	Dus	See Figure 1		14	20	115
^t PLH	Propagation delay time, low- to high-level output	Terminal	Bus (SRQ, NDAC, NRFD)	C _L = 30 pF, See Figure 1		29	35	ns
^t PLH	Propagation delay time, low- to high-level output	Bus	Terminal	C _L = 30 pF,		10	20	ns
^t PHL	Propagation delay time, high- to low-level output	Dus	Termina	See Figure 2		15	22	113
^t PZH	Output enable time to high level		Bus (ATN,				60	
^t PHZ	Output disable time from high level	TE,DC,	EOI, REN,	See Figure 3			45	ns
tPZL	Output enable time to low level	or SC	IFC, and	See Figure 3			60	115
tPLZ	Output disable time from low level]	DAV)				55	1
^t PZH	Output enable time to high level						55	
tPHZ	Output disable time from high level	TE,DC,	Townsiand	Coo Firme 4			50	
tpzL	Output enable time to low level	or SC	Terminal	See Figure 4				ns
tPLZ	Output disable time from low level						55	

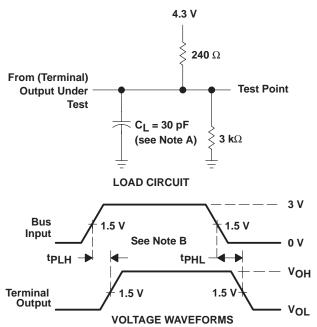
PARAMETER MEASUREMENT INFORMATION



NOTES: A. C_L includes probe and jig capacitance.

B. The input pulse is supplied by a generator having the following characteristics: PRR \leq 1 MHz, 50% duty cycle, $t_{\Gamma} \leq$ 6 ns, $t_{\Gamma} \leq$ 6 ns, $t_{\Gamma} \leq$ 6 ns, $t_{\Gamma} \leq$ 7 or $t_{\Gamma} \leq$ 8 ns, $t_{\Gamma} \leq$ 9 or t_{Γ}

Figure 1. Terminal-to-Bus Load Circuit and Voltage Waveforms



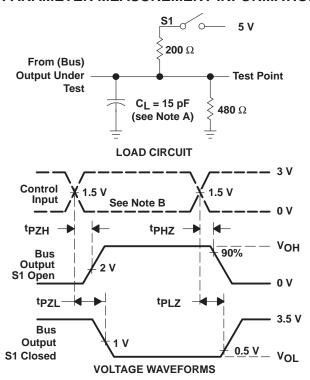
NOTES: A. C_L includes probe and jig capacitance.

B. The input pulse is supplied by a generator having the following characteristics: PRR \leq 1 MHz, 50% duty cycle, $t_{\Gamma} \leq$ 6 ns, $t_{\Gamma} \leq$ 6 ns, $t_{\Gamma} \leq$ 6 ns, $t_{\Gamma} \leq$ 7 ms, $t_{\Gamma} \leq$ 8 ns, $t_{\Gamma} \leq$ 8 ns, $t_{\Gamma} \leq$ 9 ns, $t_{\Gamma} \leq$

Figure 2. Bus-to-Terminal Load Circuit and Voltage Waveforms



PARAMETER MEASUREMENT INFORMATION

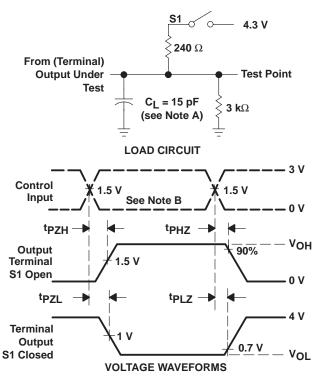


NOTES: A. C_L includes probe and jig capacitance.

B. The input pulse is supplied by a generator having the following characteristics: PRR \leq 1 MHz, 50% duty cycle, $t_{\Gamma} \leq$ 6 ns, $t_{\Gamma} \leq$ 6 ns, $t_{\Gamma} \leq$ 6 ns, $t_{\Gamma} \leq$ 7 ms, $t_{\Gamma} \leq$ 8 ns, $t_{\Gamma} \leq$ 8 ns, $t_{\Gamma} \leq$ 9 ns, $t_{\Gamma} \leq$

Figure 3. Bus Enable and Disable Times Load Circuit and Voltage Waveforms

PARAMETER MEASUREMENT INFORMATION

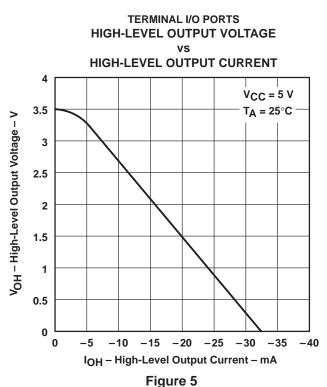


NOTES: A. C_L includes probe and jig capacitance.

B. The Input pulse is supplied by a generator having the following characteristics: PRR \leq 1 MHz, 50% duty cycle, $t_f \leq$ 6 ns, $t_f \leq$ 6 ns, $t_O =$ 50 Ω .

Figure 4. Terminal Enable and Disable Times Load Circuit and Voltage Waveforms

TYPICAL CHARACTERISTICS



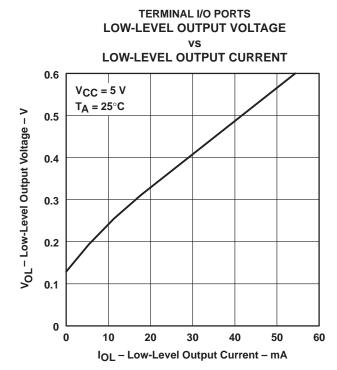
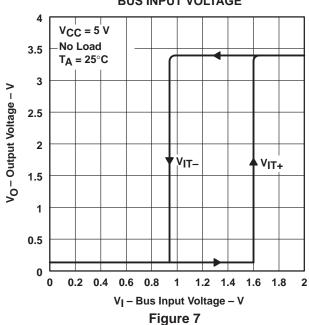


Figure 6

TERMINAL I/O PORTS OUTPUT VOLTAGE VS BUS INPUT VOLTAGE

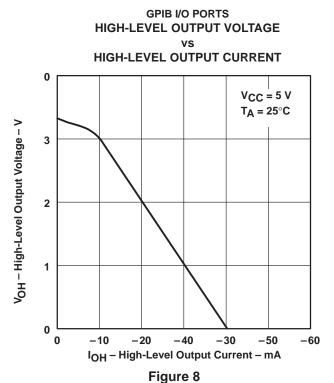


GPIB I/O PORTS
LOW-LEVEL OUTPUT VOLTAGE

TYPICAL CHARACTERISTICS

0

20 30



LOW-LEVEL OUTPUT CURRENT

0.6

VCC = 5 V

TA = 25°C

0.2

- O.5

0.1

0.2

40 50 60

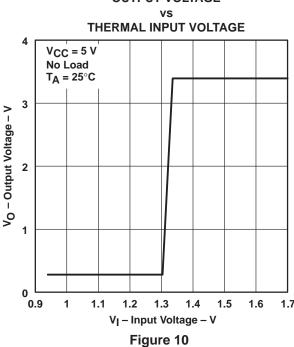
IOL - Low-Level Output Current - mA

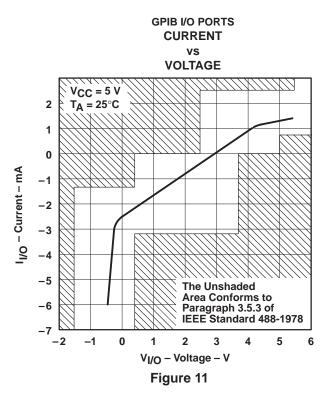
Figure 9

70

80 90

GPIB I/O PORTS
OUTPUT VOLTAGE





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PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
SN75161BDW	ACTIVE	SOIC	DW	20	25	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	SN75161B	Samples
SN75161BDWG4	ACTIVE	SOIC	DW	20	25	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	SN75161B	Samples
SN75161BDWR	ACTIVE	SOIC	DW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	SN75161B	Samples
SN75161BDWRE4	ACTIVE	SOIC	DW	20	2000	TBD	Call TI	Call TI	0 to 70		Samples
SN75161BDWRG4	ACTIVE	SOIC	DW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	SN75161B	Samples
SN75161BN	ACTIVE	PDIP	N	20	20	RoHS & Non-Green	NIPDAU	N / A for Pkg Type	0 to 70	SN75161BN	Samples
SN75161BNE4	ACTIVE	PDIP	N	20	20	RoHS & Non-Green	NIPDAU	N / A for Pkg Type	0 to 70	SN75161BN	Samples
SN75162BDW	ACTIVE	SOIC	DW	24	25	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	SN75162B	Samples
SN75162BDWE4	ACTIVE	SOIC	DW	24	25	TBD	Call TI	Call TI	0 to 70		Samples
SN75162BDWR	ACTIVE	SOIC	DW	24	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	SN75162B	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.



PACKAGE OPTION ADDENDUM

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- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

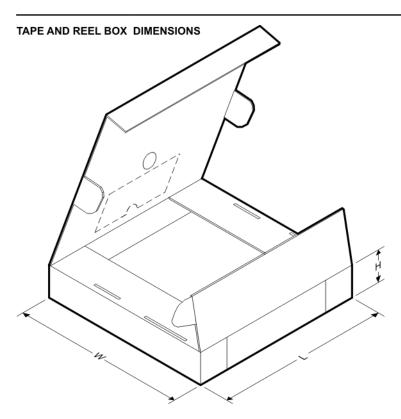
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN75161BDWR	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1
SN75162BDWR	SOIC	DW	24	2000	330.0	24.4	10.75	15.7	2.7	12.0	24.0	Q1

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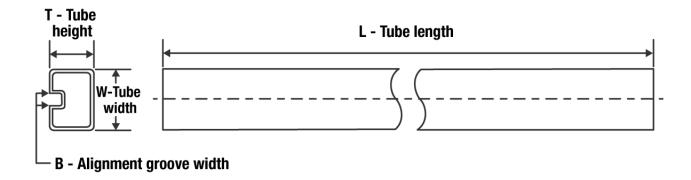


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN75161BDWR	SOIC	DW	20	2000	367.0	367.0	45.0
SN75162BDWR	SOIC	DW	24	2000	350.0	350.0	43.0

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TUBE



*All dimensions are nominal

di dimensions are nominal								
Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
SN75161BDW	DW	SOIC	20	25	507	12.83	5080	6.6
SN75161BDW	DW	SOIC	20	25	506.98	12.7	4826	6.6
SN75161BDWG4	DW	SOIC	20	25	506.98	12.7	4826	6.6
SN75161BDWG4	DW	SOIC	20	25	507	12.83	5080	6.6
SN75161BN	N	PDIP	20	20	506	13.97	11230	4.32
SN75161BNE4	N	PDIP	20	20	506	13.97	11230	4.32
SN75162BDW	DW	SOIC	24	25	506.98	12.7	4826	6.6
SN75162BDWE4	DW	SOIC	24	25	506.98	12.7	4826	6.6

DW (R-PDSO-G24)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters). Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MS-013 variation AD.



N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.





SOIC



NOTES:

- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
- 5. Reference JEDEC registration MS-013.



SOIC



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOIC



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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